



LM833 Dual Audio Operational Amplifier

General Description

The LM833 is a dual general purpose operational amplifier designed with particular emphasis on performance in audio systems.

This dual amplifier IC utilizes new circuit and processing techniques to deliver low noise, high speed and wide bandwidth without increasing external components or decreasing stability. The LM833 is internally compensated for all closed loop gains and is therefore optimized for all preamp and high level stages in PCM and HiFi systems.

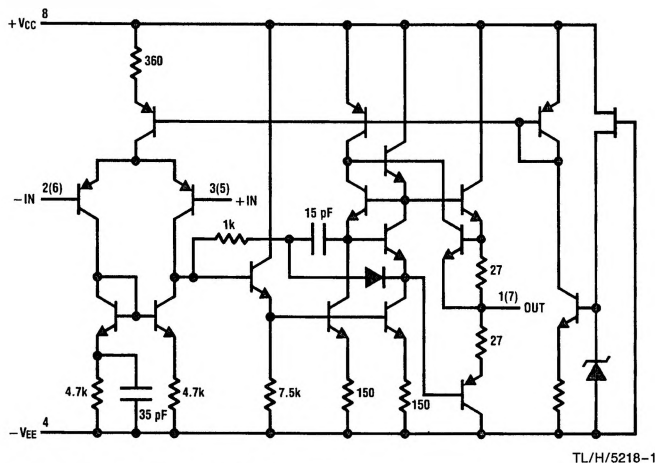
The LM833 is pin-for-pin compatible with industry standard dual operational amplifiers.

Features

- Wide dynamic range
- Low input noise voltage
- High slew rate
- High gain bandwidth product
- Wide power bandwidth
- Low distortion
- Low offset voltage
- Large phase margin

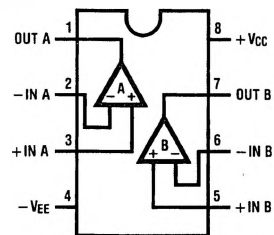
$> 140 \text{ dB}$
 $4.5 \text{ nV}/\sqrt{\text{Hz}}$
 $7 \text{ V}/\mu\text{s (typ)}$
 $5 \text{ V}/\mu\text{s (min)}$
 15 MHz (typ)
 10 MHz (min)
 120 kHz
 0.002%
 0.3 mV
 60°

Schematic Diagram (1/2 LM833)



TL/H/5218-1

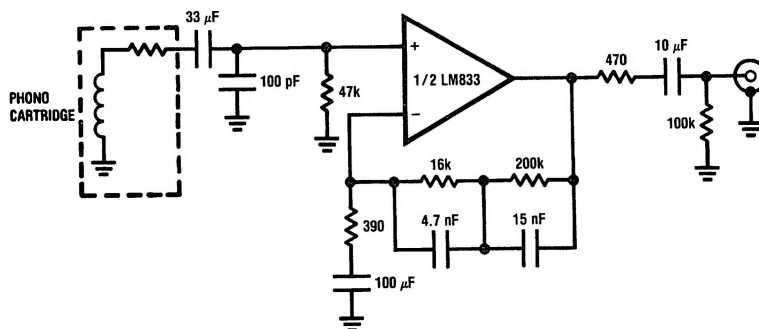
Connection Diagram



TL/H/5218-2

Order Number LM833M or LM833N
See NS Package Number
M08A or N08E

Typical Application RIAA Preamp



TL/H/5218-3

$A_v = 35 \text{ dB}$
 $E_n = 0.33 \mu\text{V}$
 $S/N = 90 \text{ dB}$
 $f = 1 \text{ kHz}$
 A Weighted
 A Weighted, $V_{IN} = 10 \text{ mV}$
 @ $f = 1 \text{ kHz}$

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	$V_{CC}-V_{EE}$	36V
Differential Input Voltage (Note 1)	V_{ID}	$\pm 30V$
Input Voltage Range (Note 1)	V_{IC}	$\pm 15V$
Power Dissipation (Note 2)	P_D	500 mW
Operating Temperature Range	T_{OPR}	$-40 \sim 85^{\circ}C$
Storage Temperature Range	T_{STG}	$-60 \sim 150^{\circ}C$

Soldering Information

Dual-In-Line Package	
Soldering (10 seconds)	260°C
Small Outline Package	
Vapor Phase (60 seconds)	215°C
Infrared (15 seconds)	220°C
See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.	
ESD tolerance (Note 3)	1600V

DC Electrical Characteristics ($T_A = 25^{\circ}C$, $V_S = \pm 15V$)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
V_{OS}	Input Offset Voltage	$R_S = 10\Omega$		0.3	5	mV
I_{OS}	Input Offset Current			10	200	nA
I_B	Input Bias Current			500	1000	nA
A_V	Voltage Gain	$R_L = 2\text{ k}\Omega$, $V_O = \pm 10V$	90	110		dB
V_{OM}	Output Voltage Swing	$R_L = 10\text{ k}\Omega$ $R_L = 2\text{ k}\Omega$	± 12 ± 10	± 13.5 ± 13.4		V V
V_{CM}	Input Common-Mode Range		± 12	± 14.0		V
CMRR	Common-Mode Rejection Ratio	$V_{IN} = \pm 12V$	80	100		dB
PSRR	Power Supply Rejection Ratio	$V_S = 15 \sim 5V$, $-15 \sim -5V$	80	100		dB
I_Q	Supply Current	$V_O = 0V$, Both Amps		5	8	mA

AC Electrical Characteristics ($T_A = 25^{\circ}C$, $V_S = \pm 15V$, $R_L = 2\text{ k}\Omega$)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
SR	Slew Rate	$R_L = 2\text{ k}\Omega$	5	7		V/ μs
GBW	Gain Bandwidth Product	$f = 100\text{ kHz}$	10	15		MHz

Design Electrical Characteristics ($T_A = 25^{\circ}C$, $V_S = \pm 15V$)

The following parameters are not tested or guaranteed.

Symbol	Parameter	Conditions	Typ	Units
$\Delta V_{OS}/\Delta T$	Average Temperature Coefficient of Input Offset Voltage		2	$\mu V/^{\circ}C$
THD	Distortion	$R_L = 2\text{ k}\Omega$, $f = 20 \sim 20\text{ kHz}$ $V_{OUT} = 3\text{ V}_{rms}$, $A_V = 1$	0.002	%
e_n	Input Referred Noise Voltage	$R_S = 100\Omega$, $f = 1\text{ kHz}$	4.5	nV/ $\sqrt{Hz}$
i_n	Input Referred Noise Current	$f = 1\text{ kHz}$	0.7	pA/ $\sqrt{Hz}$
PBW	Power Bandwidth	$V_O = 27\text{ V}_{pp}$, $R_L = 2\text{ k}\Omega$, THD $\leq 1\%$	120	kHz
f_U	Unity Gain Frequency	Open Loop	9	MHz
ϕ_M	Phase Margin	Open Loop	60	deg
	Input Referred Cross Talk	$f = 20 \sim 20\text{ kHz}$	-120	dB

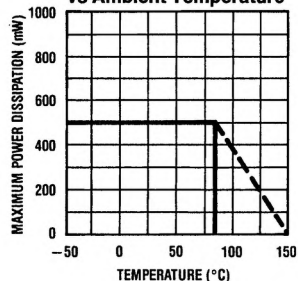
Note 1: If supply voltage is less than $\pm 15V$, it is equal to supply voltage.

Note 2: This is the permissible value at $T_A \leq 85^{\circ}C$.

Note 3: Human body model, 1.5 k Ω in series with 100 pF.

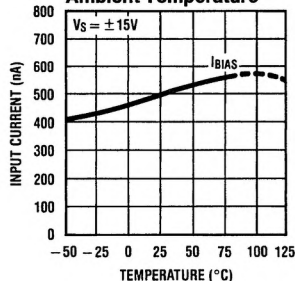
Typical Performance Characteristics

Maximum Power Dissipation vs Ambient Temperature



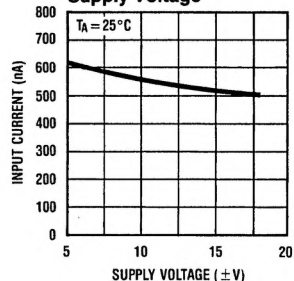
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Input Bias Current vs Ambient Temperature



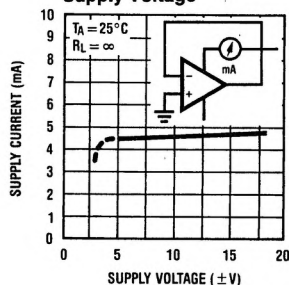
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Input Bias Current vs Supply Voltage



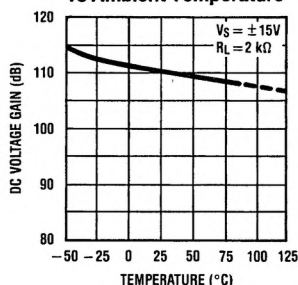
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Supply Current vs Supply Voltage



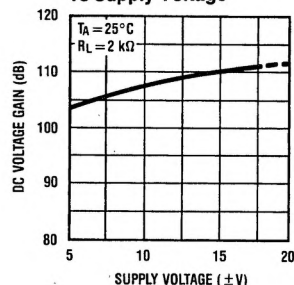
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DC Voltage Gain vs Ambient Temperature



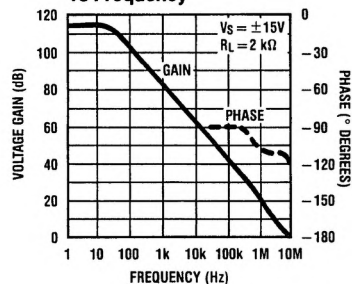
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DC Voltage Gain vs Supply Voltage



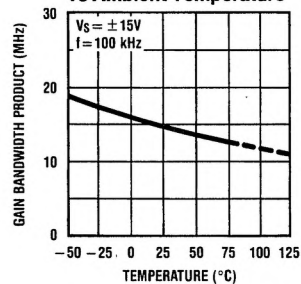
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Voltage Gain & Phase vs Frequency



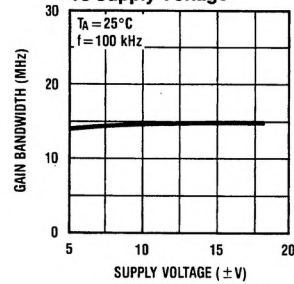
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Gain Bandwidth Product vs Ambient Temperature



TL/H/5218-11

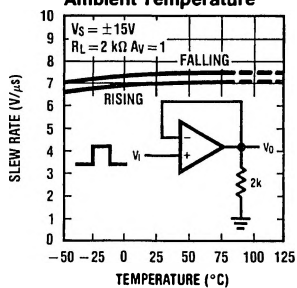
Gain Bandwidth vs Supply Voltage



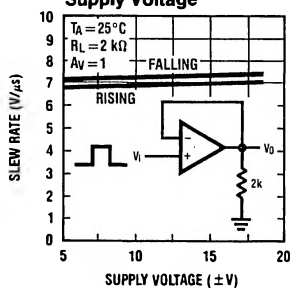
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Typical Performance Characteristics (Continued)

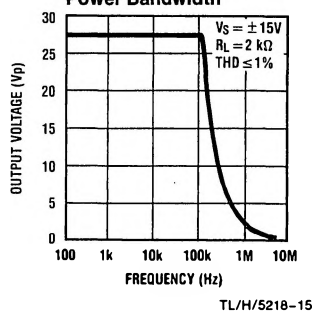
Slew Rate vs Ambient Temperature



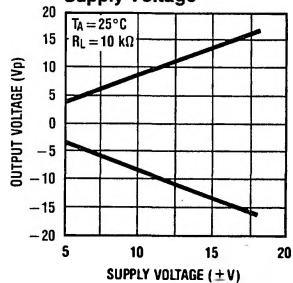
Slew Rate vs Supply Voltage



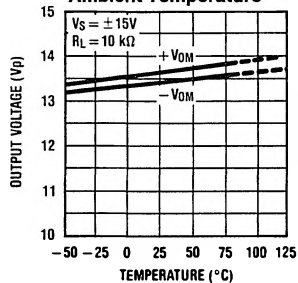
Power Bandwidth



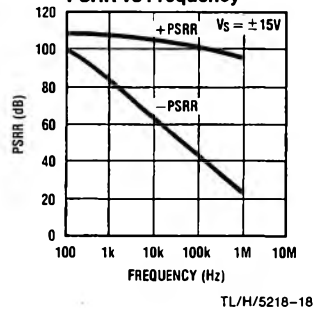
Maximum Output Voltage vs Supply Voltage



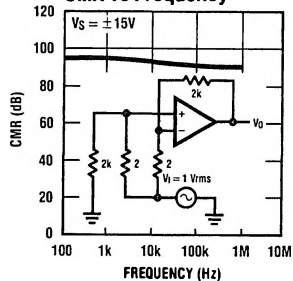
Maximum Output Voltage vs Ambient Temperature



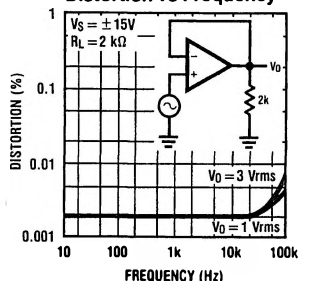
PSRR vs Frequency



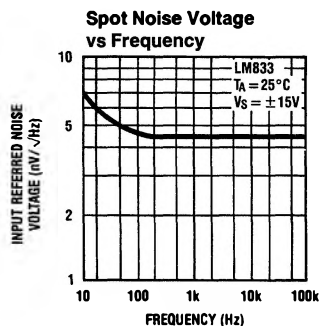
CMR vs Frequency



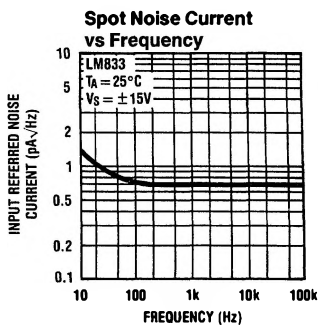
Distortion vs Frequency



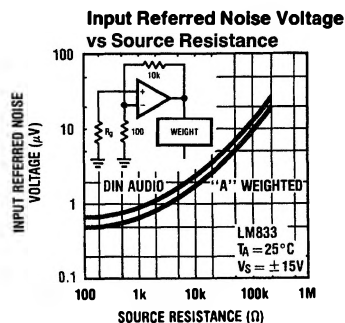
Typical Performance Characteristics (Continued)



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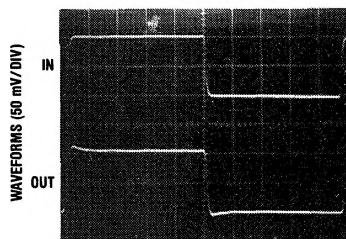


TL/H/5218-22



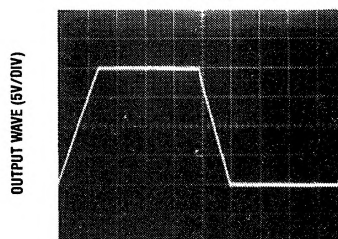
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Noninverting Amp



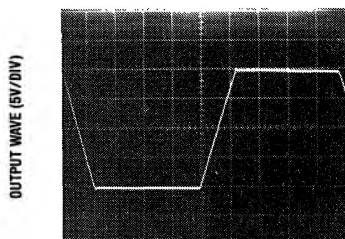
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Noninverting Amp



TL/H/5218-25

Inverting Amp



TL/H/5218-26

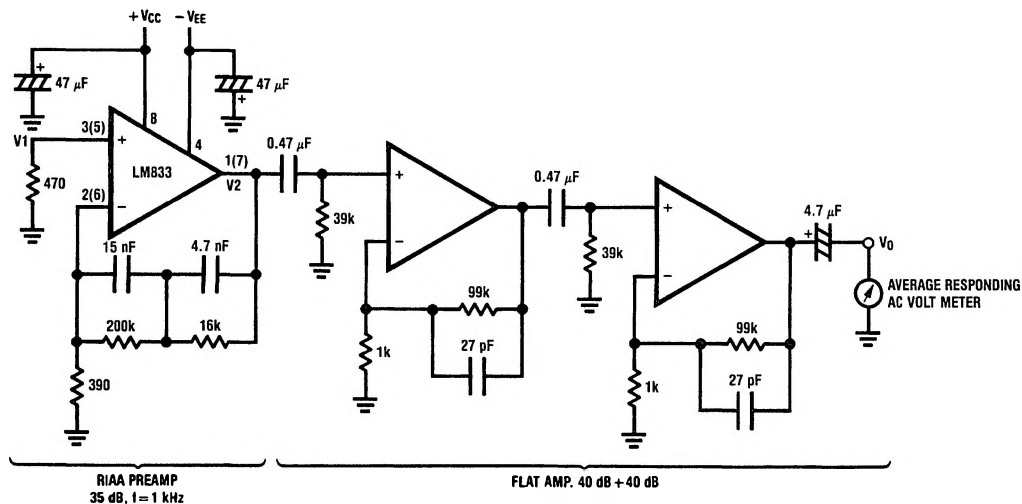
Application Hints

The LM833 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 50 pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 50 pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

Noise Measurement Circuit

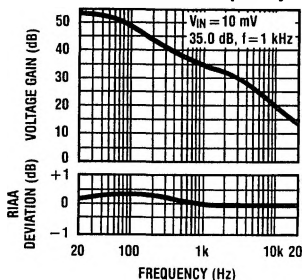
Complete shielding is required to prevent induced pick up from external sources. Always check with oscilloscope for power line noise.



TL/H/5218-27

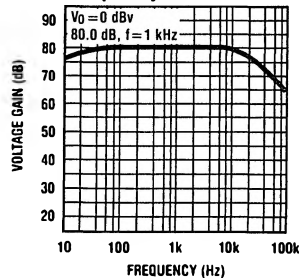
Total Gain: 115 dB @ $f = 1$ kHz
Input Referred Noise Voltage: $e_n = V_0/560,000$ (V)

RIAA Preamp Voltage Gain, RIAA Deviation vs Frequency



TL/H/5218-28

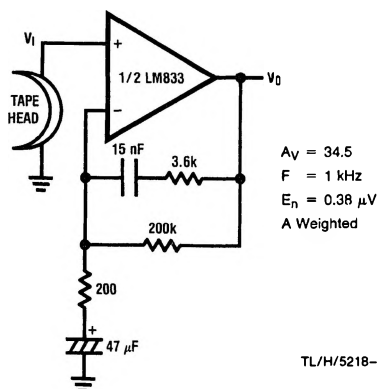
Flat Amp Voltage Gain vs Frequency



TL/H/5218-29

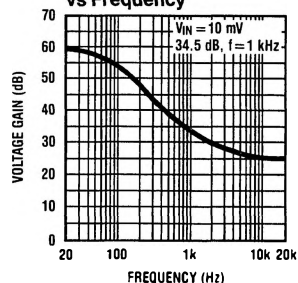
Typical Applications

NAB Preamp



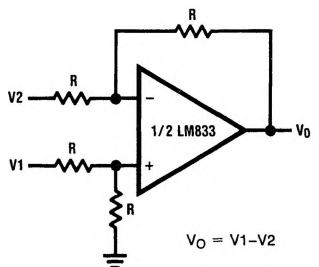
TL/H/5218-30

NAB Preamp Voltage Gain vs Frequency



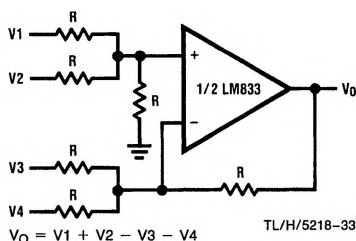
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Balanced to Single Ended Converter



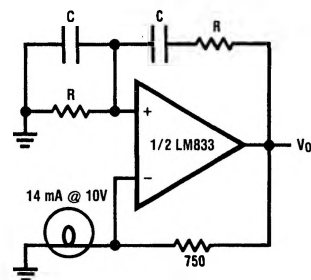
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Adder/Subtractor



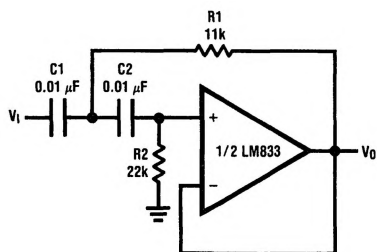
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Sine Wave Oscillator



TL/H/5218-34

Second Order High Pass Filter (Butterworth)



TL/H/5218-35

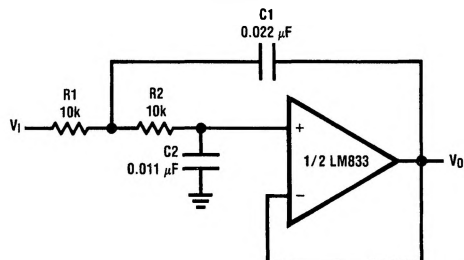
if $C_1 = C_2 = C$

$$R_1 = \frac{\sqrt{2}}{2\omega_0 C}$$

$$R_2 = 2 \cdot R_1$$

Illustration is $f_0 = 1 \text{ kHz}$

Second Order Low Pass Filter (Butterworth)



TL/H/5218-36

if $R_1 = R_2 = R$

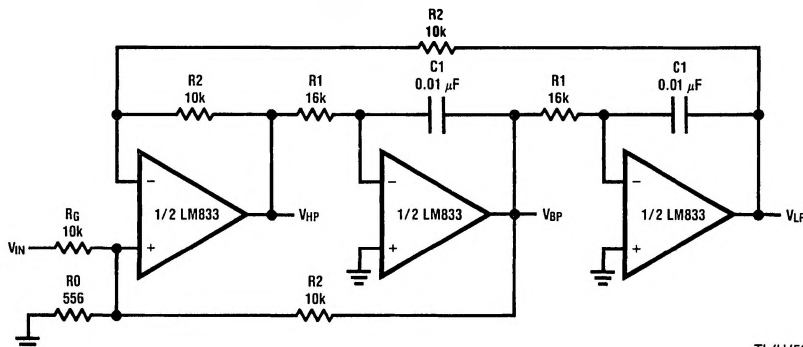
$$C_1 = \frac{\sqrt{2}}{\omega_0 R}$$

$$C_2 = \frac{C_1}{2}$$

Illustration is $f_0 = 1 \text{ kHz}$

Typical Applications (Continued)

State Variable Filter

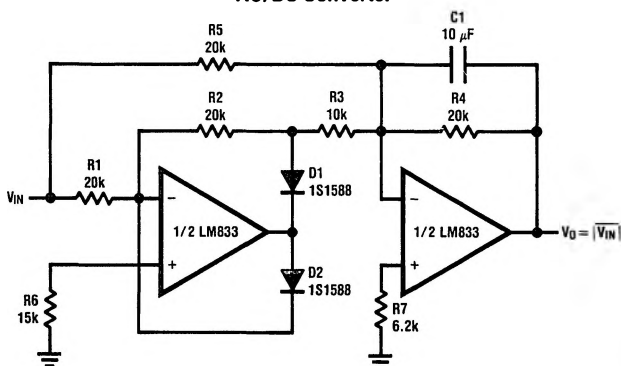


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$$f_0 = \frac{1}{2\pi C_1 R_1'} Q = \frac{1}{2} \left(1 + \frac{R_2}{R_0} + \frac{R_2}{R_G} \right), A_{BP} = Q A_{LP} = Q A_{LH} = \frac{R_2}{R_G}$$

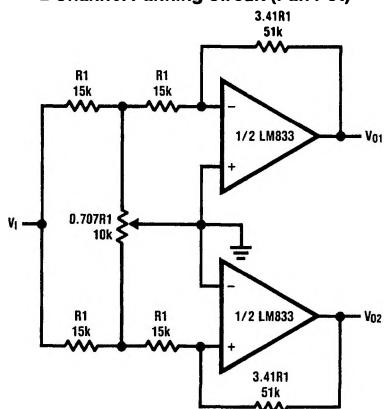
Illustration is $f_0 = 1 \text{ kHz}$, $Q = 10$, $A_{BP} = 1$

AC/DC Converter



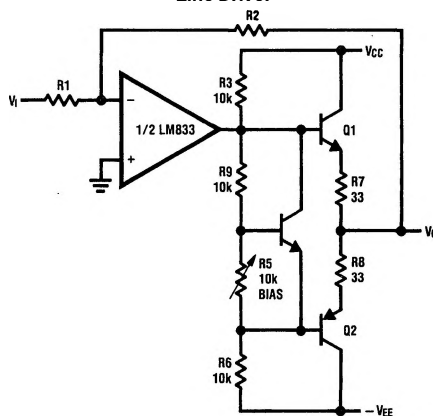
TL/H/5218-38

2 Channel Panning Circuit (Pan Pot)



TL/H/5218-39

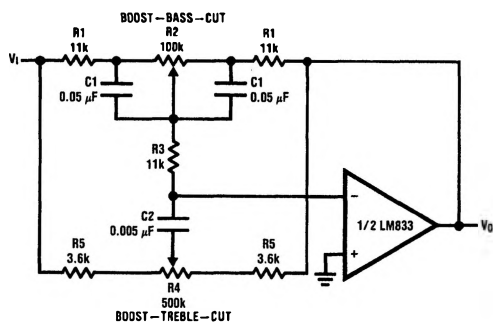
Line Driver



TL/H/5218-40

Typical Application (Continued)

Tone Control



TL/H/5218-41

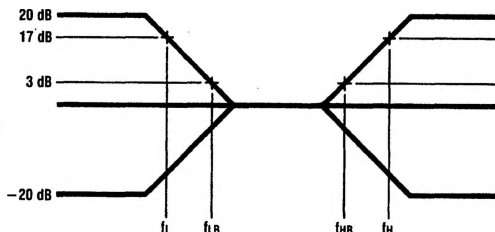
$$f_L = \frac{1}{2\pi R_2 C_1}, f_{LB} = \frac{1}{2\pi R_1 C_1}$$

$$f_H = \frac{1}{2\pi R_5 C_2}, f_{HB} = \frac{1}{2\pi (R_1 + R_5 + 2R_3) C_2}$$

Illustration is:

$$f_L = 32 \text{ Hz}, f_{LB} = 320 \text{ Hz}$$

$$f_H = 11 \text{ kHz}, f_{HB} = 1.1 \text{ kHz}$$



TL/H/5218-42

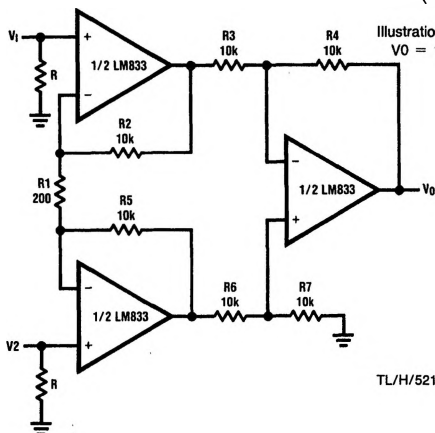
Balanced Input Mic Amp

If $R_2 = R_5, R_3 = R_6, R_4 = R_7$

$$V_0 = \left(1 + \frac{2R_2}{R_1}\right) \frac{R_4}{R_3} (V_2 - V_1)$$

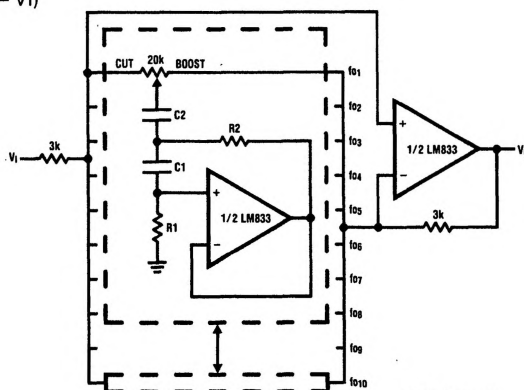
Illustration is:

$$V_0 = 101(V_2 - V_1)$$



TL/H/5218-43

10 Band Graphic Equalizer



TL/H/5218-44

f ₀ (Hz)	C ₁	C ₂	R ₁	R ₂
32	0.12 μF	4.7 μF	75kΩ	500Ω
64	0.056 μF	3.3 μF	68kΩ	510Ω
125	0.033 μF	1.5 μF	62kΩ	510Ω
250	0.015 μF	0.82 μF	68kΩ	470Ω
500	8200 pF	0.39 μF	62kΩ	470Ω
1k	3900 pF	0.22 μF	68kΩ	470Ω
2k	2000 pF	0.1 μF	68kΩ	470Ω
4k	1100 pF	0.056 μF	62kΩ	470Ω
8k	510 pF	0.022 μF	68kΩ	510Ω
16k	330 pF	0.012 μF	51kΩ	510Ω

At volume of change = ±12 dB

Q = 1.7

Reference: "AUDIO/RADIO HANDBOOK", National Semiconductor, 1980, Page 2-61